

# 10-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

## FEATURES:

- Bus switches provide zero delay paths
- Low switch on-resistance:  $7\Omega$
- TTL-compatible input and output levels
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Available in QSOP and TSSOP packages

# **DESCRIPTION:**

The FST6800 belongs to IDT's family of Bus switches. Bus switch devices perform the function of connecting or isolating two ports without providing any inherent current sink or source capability. Thus they generate little or no noise of their own while providing a low resistance path for an external driver. These devices connect input and output ports through an n-channel FET. When the gate-to-source junction of this FET is adequately forward-biased the device conducts and the resistance between input and output ports is small. Without adequate bias on the gate-to-source junction of the FET, the FET is turned off, therefore with no Vcc applied, the device has hot insertion capability.

The low on-resistance and simplicity of the connection between input and output ports reduces the delay in this path to close to zero.

The FST6800 provides a 10-Bit TTL-compatible interface. The  $\overline{ON}$  pin serves as the enable pin. When  $\overline{ON}$  is high, A and B ports are isolated and B outputs are precharged to the BIASV voltage, through the equivalent of a 10K $\Omega$  resistor.

# FUNCTIONAL BLOCK DIAGRAM



# PINCONFIGURATION



QSOP/ TSSOP TOP VIEW

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INDUSTRIAL TEMPERATURE RANGE

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### **INDUSTRIAL TEMPERATURE RANGE**

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	–0.5 to +7	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	Maximum Continuous Channel Current	128	mA

### NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc, Control, and Switch terminals.

## CAPACITANCE<sup>(1)</sup>

Symbol	Parameter	Conditions <sup>(2)</sup>	Тур.	Unit
Cin	Control Input Capacitance		4	pF
CI/O	Switch Input/Output Capacitance	Switch Off		pF

### NOTES:

1. Capacitance is characterized but not tested.

2. TA =  $25^{\circ}$ C, f = 1MHz, VIN = 0V, VOUT = 0V.

## PINDESCRIPTION

Pin Names	I/O	Description	
A1-10, B1-10	I/O	Buses A, B	
ŌN	I	Bus Switch Enable (Active LOW)	
BIASV	I	BIAS Voltage	

## FUNCTION TABLE<sup>(1)</sup>

ŌN	B1-10	Description
L	A1-10	Connect
Н	BIASV Precharge	

NOTE:

1. H = HIGH Voltage Level L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, VCC = 5.0V  $\pm$  5%, BIASV = 0 to VCC

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Тур. <sup>(2)</sup>	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs		2	_		V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control	l Inputs	_	_	0.8	V
Ін	Input HIGH Current	Vcc = Max.	VI = VCC	-	-	±1	μA
lil	Input LOW Current		VI = GND	-	-	±1	
lo	Precharge Output Current	Vcc = Min., BIASV = 2.4V, Vo = 0V		0.15	—	_	mA
Іоzн	High Impedance Output Current	Vcc = Max.	Vo = Vcc	-	_	±1	μA
Iozl	(3-State Output Pins)	Vo = GND		—	_	±1	
los	Short Circuit Current	Vcc = Min., Vo = GND <sup>(3)</sup>		_	300		mA
Vik	Clamp Diode Voltage	Vcc = Min., IIN = -18mA		-	-0.7	-1.2	V
Ron	Switch On Resistance <sup>(4)</sup>	VCC = 4.75V, VIN = 0.0V ION = 64mA		_	_	7	Ω
		Vcc = 4.75V, VIN = 2.4V ION = 15mA		_	_	15	
IOFF	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo $\leq 4.5$ V		_	_	1	μA
lcc	Quiescent Power Supply Current	Vcc = Max., VI = GND or Vcc		-	0.1	3	μA

### NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.

4. Measured by voltage drop between ports at indicated current through the switch.

# POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Тур. <sup>(2)</sup>	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = Max.$ $V_{IN} = 3.4V^{(3)}$		-	0.5	1.5	mA
ICCD	Dynamic Power Supply Current <sup>(4)</sup>	Vcc = Max., Outputs Open Enable Pin Toggling 50% Duty Cycle	Vin = Vcc Vin = GND	_	30	40	μΑ/ MHz/ Enable
lc	Total Power Supply Current <sup>(6)</sup>	Vcc = Max., Outputs Open Enable Pin Toggling (Ten Switches Toggling)	VIN = VCC VIN = GND	—	3	4	mA
		fi = 10MHz 50% Duty Cycle	Vin = 3.4V Vin = GND	_	3.3	4.8	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

- 5. Values for these conditions are examples of Icc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
  - $IC = ICC + \Delta ICC DHNT + ICCD (fiN)$
  - Icc = Quiescent Current
  - $\Delta Icc$  = Power Supply Current for a TTL High Input (VIN = 3.4V)
  - DH = Duty Cycle for TTL Inputs High
  - NT = Number of TTL Inputs at DH
  - IccD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
  - fcp = Clock Frequency for Register Devices (zero for non-register devices)
  - fi = Input Frequency
  - N = Number of SwitchesToggling at fi
  - All currents are in milliamps and all frequencies are in megahertz

## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $\label{eq:Following Conditions Apply Unless Otherwise Specified:$ 

Industrial: TA = -40°C to +85°C, VCC =  $5.0V \pm 5\%$ 

Symbol	Description	Condition <sup>(1)</sup>	Min. <sup>(2)</sup>	Тур.	Max.	Unit
<b>t</b> PLH	Data Propagation Delay	C∟ = 50pF	—	—	0.25	ns
<b>t</b> PHL	Ax, Bx to Bx, Ax <sup>(3,4)</sup>	RL = 500Ω				
tрzн	Switch Turn On Delay		1.5	_	6.5	ns
tezl	ON to Ax, Bx					
<b>t</b> PHZ	Switch Turn Off Delay		1.5	_	5.5	ns
<b>t</b> PLZ	ON to Ax, Bx <sup>(3)</sup>					

### NOTES:

1. See test circuit and waveforms.

2. Minimum limits guaranteed but not tested.

3. This parameter is guaranteed by design but not tested.

<sup>4.</sup> The bus switch contributes no propagation delay other than the RC delay of the on resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 50 pF load. Since this time is constant and much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

## **TEST CIRCUITS AND WAVEFORMS**



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### Test Circuits for All Outputs







Propagation Delay

# SWITCHPOSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

### DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



Pulse Width

Octal Link



### Enable and Disable Times

#### NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.





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